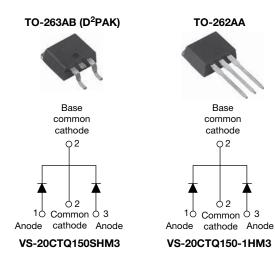


epoxy

High Performance Schottky Rectifier, 2 x 10 A



PRODUCT SUMMARY								
Package	TO-263AB (D ² PAK), TO-262AA							
I _{F(AV)}	2 x 10 A							
V _R	150 V							
V _F at I _F	0.66 V							
I _{RM} max.	5.0 mA at 125 °C							
T _J max.	175 °C							
E _{AS}	1.0 mJ							
Diode variation	Common cathode							

FEATURES

High

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High frequency operation



encapsulation for enhanced mechanical strength and moisture resistance
 Guard ring for enhanced ruggedness and long term

purity, high temperature

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified meets JESD-201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	20	A				
V _{RRM}		150	V				
I _{FSM}	t _p = 5 μs sine	1030	A				
V _F	10 A _{pk} , T_J = 125 °C (per leg)	0.66	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-20CTQ150SHM3 VS-20CTQ150-1HM3	UNITS			
Maximum DC reverse voltage	V _R	- 150	V			
Maximum working peak reverse voltage	V _{RWM}	150	v			

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS			
Maximum average forward per leg		I _{F(AV)}			10				
current See fig. 5	current See fig. 5 per device		50 % duty cycle at T_C = 154 °C, rectangular waveform		20	А			
Maximum peak one cycle			5 µs sine or 3 µs rect. pulse	Following any rated	1030	A			
See fig. 7	non-repetitive surge current per leg See fig. 7		10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	180				
Non-repetitive avalanche energ	Non-repetitive avalanche energy per leg		T _J = 25 °C, I _{AS} = 1 A, L = 2 mH		1.0	mJ			
Repetitive avalanche current pe	er leg	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		1	А			

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ELECTRICAL SPECIFICATIONS	5					
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS
		10 A	T _J = 25 °C	0.80	0.88	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	20 A	1j=25 0	0.90	1.0	V
See fig. 1	VFM (')	10 A	T _{.1} = 125 °C	0.63	0.66	
		20 A	1j = 125 C	0.73	0.77	
Maximum reverse leakage current per leg	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3.0	25	μA
See fig. 2	IRM (1)	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	2.7	5.0	mA
Typical junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz), 25 °C	-	280	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 m	m from package body	-	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

Note

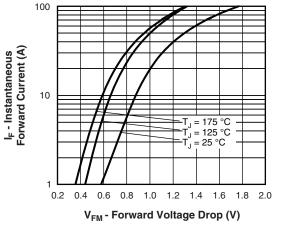
 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

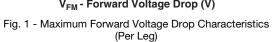
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C			
Maximum thermal resistance,	per leg	П	DC operation	2.0				
junction to case	per package	R _{thJC} DC operation		1.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-262)	0.50	0,11			
Approvimato weight				2	g			
Approximate weight				0.07	oz.			
Manuation to some	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
•• •• •			Case style D ² PAK	20CTQ	150SH			
Marking device			Case style TO-262	20CTQ ²	I50-1H			

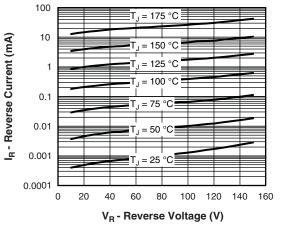
VS-20CTQ150SHM3, VS-20CTQ150-1HM3

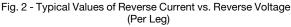












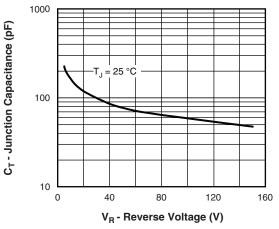


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

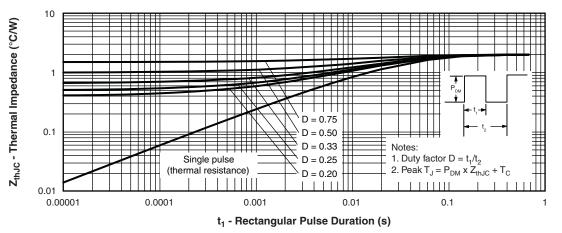
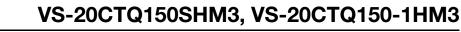
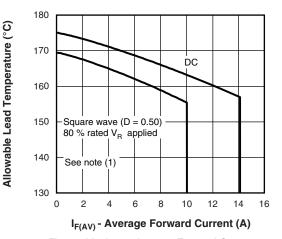


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

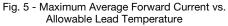
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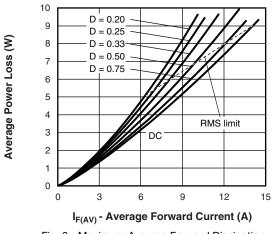




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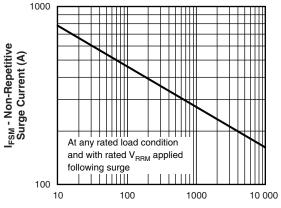




Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

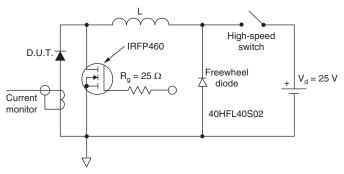


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \\ \end{array}$

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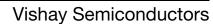
ORDERING INFORMATION TABLE

Device code	VS-	20	С	т	Q	150	S	TRL	н	МЗ		
		2	3	4	5	6	7	8	9	10		
	1 ·	- Visł	nay Sen	niconduc	ctors pro	oduct						
	2 - Current rating (20 = 20 A)											
	3 ·											
	4 ·											
	5	- Sch	ottky "C)" series								
	6	- Volt	Voltage rating (150 = 150 V)									
	7 ·	• s	= D ² PA	K								
		• -1	= TO-2	62								
	8	• N	one = tu	ıbe								
		 TRL = tape and reel (left oriented - for D²PAK only) 										
		• TI	 TRR = tape and reel (right oriented - for D²PAK only) 									
	9.	• H=	AEC-Q	101 qua	alified							
	10 ·	- M3	= halog	en-free,	RoHS	-complia	ant and	termina	ition lea	ld (Pb)-fi		

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-20CTQ150SHM3	50	1000	Antistatic plastic tubes					
VS-20CTQ150STRLHM3	800	800	13" diameter reel					
VS-20CTQ150STRRHM3	800	800	13" diameter reel					
VS-20CTQ150-1HM3	50	1000	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS							
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046					
	TO-262AA	www.vishay.com/doc?95419					
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?95032					

Outline Dimensions

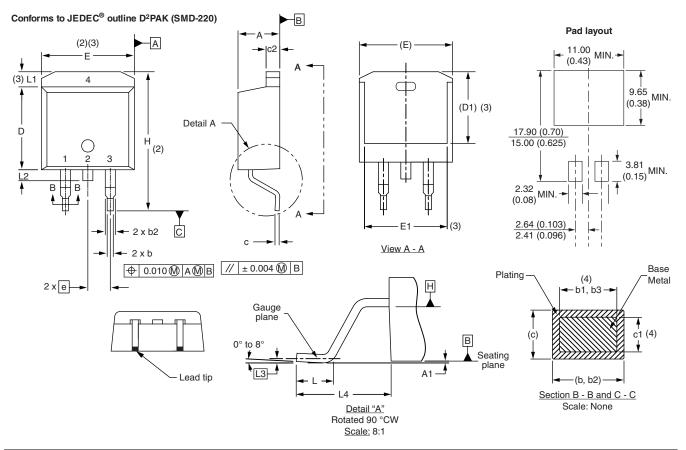


D²PAK

DIMENSIONS in millimeters and inches

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SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES SYMBOL		MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010) BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

(4) Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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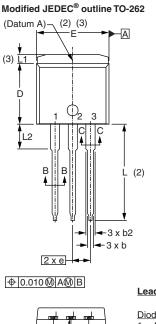
Outline Dimensions

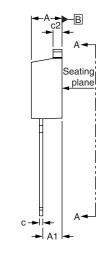


Vishay Semiconductors

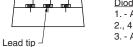
TO-262

DIMENSIONS in millimeters and inches

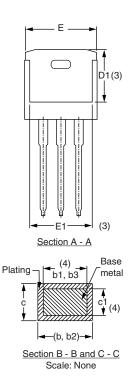




Lead assignments



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode



SYMBOL	MILLIN	IETERS	INC	NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
 ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

⁽⁶⁾ Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

measured at the outmost extremes of the plastic body $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1

not exceed 0.127 mm (0.005") per side. These dimensions are

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